

**PATENT APPLICATION**

Sheet 1 of 9

<p><b>FORM PTO-1449</b></p> <p><b>LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT</b></p> <p>(Use several sheets if necessary)</p>	<p><b>ATTY. DOCKET NO.</b> 200315134-1</p>	<p><b>APPLICATION NO.</b> 10/799,325</p>	<p><b>CONFIRMATION NO.</b></p>
<p><b>APPLICANT</b> Randy L. Hoffman</p>			
<p><b>FILING DATE</b> Herewith</p>		<p><b>GROUP</b></p>	

**REFERENCE DESIGNATION                      U.S. PATENT DOCUMENTS**

EXAMINER INITIAL		DOCUMENT NUMBER	PUBLICATION DATE	NAME	Pages, Columns, Lines Where Relevant Passages or Figures Appear
TT	1A	4,559,238	12/17/2985	Bujatti, et al.	
TT	1B	5,107,314	04/21/1992	Kahng, et al.	
TT	1C	5,744,864	08/28/1998	Cillessen, et al.	
TT	1D	2003/0047785	03/11/2003	Kawasaki, et al.	03/2003
TT	1E	2003/0104659	06/05/2003	Arakawak, et al.	
TT	1F	2003/0111863	06/19/2003	Yagi	
TT	1G	2003/0139026	07/24/2003	Lucovsky	
TT	1H	2003/0180996	09/25/2003	Yamazaki, et al.	
TT	1I	2003/0186489	10/02/2003	Ishikawa	
TT	1J	2003/018221	11/27/2003	Wager, III, et al.	
TT	1K	2003/018222	11/27/2003	Wager, III, et al.	

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**FOREIGN PATENT DOCUMENTS**

		DOCUMENT NUMBER	PUBLICATION DATE	NAME OF PATENTEE OR APPLICANT	Pages/Columns/Lines Where Relevant Passages/Figures Appear	Check if Translation attached
TT	1L	WO 97-06544	02/20/1997	Cillessen, et al.		
TT	1M	EP1134811	09/19/2001	Kawasaki, et al.		
	1N					
	1O					
	1P					

**OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, etc.)**

TT	1Q	Aoki, Akira, et al., "Tin Oxide Thin Film Transistors", Japan J. Appl. Phys., Vol. 9, p.582 (1970).
TT	1R	Carcia, P.F., et al., "Transparent ZnO thin-film transistor fabricated by rf magnetron sputtering", Applied Physics Letters, Vol. 82, No. 7, pp. 1117-1119 (February 17, 2003).
TT	1S	Carcia, P.F., et al., "ZnO Thin Film Transistors for Flexible Electronics", Mat. Res. Soc. Symp. Proc., Vol. 769, pp. H72.1-H72.6 (2003).

<p><b>EXAMINER</b> <i>Thien Binh</i></p>	<p><b>DATE CONSIDERED</b> 10-11-2005</p>
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## PATENT APPLICATION

Sheet 2 of 9

<b>FORM PTO-1449</b>  <b>LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT</b>  (Use several sheets if necessary)	ATTY. DOCKET NO.	APPLICATION NO.	CONFIRMATION NO.
	200315134-1	10/799,325	
	APPLICANT		
	Randy L. Hoffman		
	FILING DATE	GROUP	
	Herewith		

## REFERENCE DESIGNATION U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	PUBLICATION DATE	NAME	Pages, Columns, Lines Where Relevant Passages or Figures Appear
TT	2A	2003/0224550	12/04/2003	Kokubo, et al.	
TT	2B	60/490,239	07/25/2003		Transparent Thin Film Transistor with Zinc-Tin Oxide Channel...
TT	2C	10/763,239	01/23/2004		Semiconductor Device
TT	2D	10/763,354	01/23/2004		Transistor Including a Deposited Channel Region Having a ...
	2E				
	2F				
	2G				
	2H				
	2I				
	2J				
	2K				

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5/22/07

## FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	PUBLICATION DATE	NAME OF PATENTEE OR APPLICANT	Pages/Columns/Lines Where Relevant Passages/Figures Appear	Check if Translation attached
	2L					
	2M					
	2N					
	2O					
	2P					

## OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, etc.)

TT	2Q	Fu, Shelton, et al., "MOS and MOSFET with Transistion Metal Oxides", SPIE Vol. 2697, pp. 520-527.
TT	2R	Giesbers, J.B., et al., "Dry Etching of All-Oxide Transparent Thin Film Memory Transistors", Microeletronic Engineering, Vol. 35, pp. 71-74 (1997).
TT	2S	Grosse-Holz, K.O., et al. "Semiconductive Behavior of Sb Doped SnO2 Thin Films", Mat. Res. Soc. Symp. Proc., Vol. 401, pp. 67-72 (1998).

EXAMINER	DATE CONSIDERED
Thien KML	10-11-2005